

## 6A, 50V - 1000V Standard Bridge Rectifier

### FEATURES

- AEC-Q101 qualified available
- Ideal for printed circuit board
- High case dielectric strength of 1500V<sub>RMS</sub>
- High surge current capability
- Typical IR less than 0.1μA
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

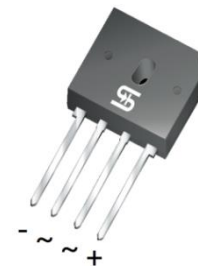
### APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application

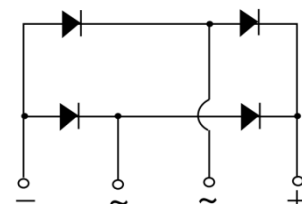
### MECHANICAL DATA

- Case: GBU
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Polarity: As marked
- Weight: 4.00g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I <sub>F</sub>	6	A
V <sub>RRM</sub>	50 - 1000	V
I <sub>FSM</sub>	175	A
T <sub>J MAX</sub>	150	°C
Package	GBU	
Configuration	Quad	



GBU



### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted)

PARAMETER	SYMBOL	GBU 601	GBU 602	GBU 603	GBU 604	GBU 605	GBU 606	GBU 607	UNIT
Marking code on the device		GBU 601	GBU 602	GBU 603	GBU 604	GBU 605	GBU 606	GBU 607	
Repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Forward current	I <sub>F</sub>	6							A
Surge peak forward current, 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	175							A
Rating for fusing (t<8.3ms)	I <sup>2</sup> t	127							A <sup>2</sup> s
Junction temperature	T <sub>J</sub>	- 55 to +150							°C
Storage temperature	T <sub>STG</sub>	- 55 to +150							°C

<b>THERMAL PERFORMANCE</b>			
<b>PARAMETER</b>	<b>SYMBOL</b>	<b>TYP</b>	<b>UNIT</b>
Junction-to-ambient thermal resistance	$R_{\theta JA}$	21	°C/W
Junction-to-case thermal resistance	$R_{\theta JC}$	2	°C/W

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise noted)						
<b>PARAMETER</b>		<b>CONDITIONS</b>	<b>SYMBOL</b>	<b>TYP</b>	<b>MAX</b>	<b>UNIT</b>
Forward voltage per diode <sup>(1)</sup>		$I_F = 3\text{A}, T_J = 25^\circ\text{C}$	$V_F$	-	1.0	V
		$I_F = 6\text{A}, T_J = 25^\circ\text{C}$		-	1.1	V
Reverse current @ rated $V_R$ per diode <sup>(2)</sup>		$T_J = 25^\circ\text{C}$	$I_R$	-	5	$\mu\text{A}$
		$T_J = 125^\circ\text{C}$		-	500	$\mu\text{A}$
Junction capacitance per diode	GBU601 GBU602 GBU603 GBU604	1MHz, $V_R = 4.0\text{V}$	$C_J$	211	-	pF
	GBU605 GBU606 GBU607			94	-	pF

**Notes:**

1. Pulse test with  $PW = 0.3\text{ms}$
2. Pulse test with  $PW = 30\text{ms}$

<b>ORDERING INFORMATION</b>		
<b>ORDERING CODE</b> <sup>(1)(2)</sup>	<b>PACKAGE</b>	<b>PACKING</b>
GBU60x	GBU	20 / Tube
GBU60xH	GBU	20 / Tube

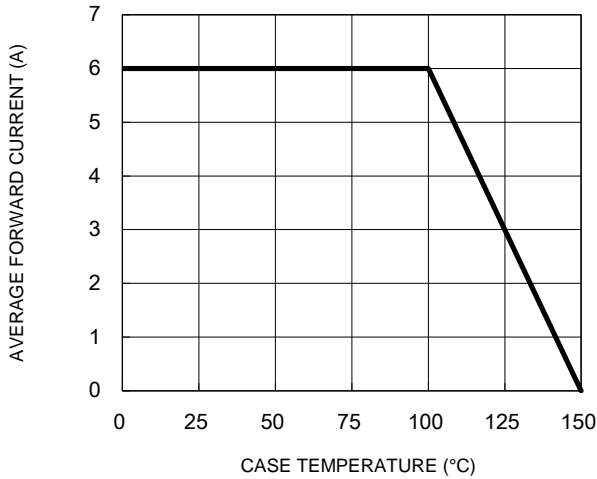
**Notes:**

1. "x" defines voltage from 50V(GBU601) to 1000V(GBU607)
2. "H" means AEC-Q101 qualified

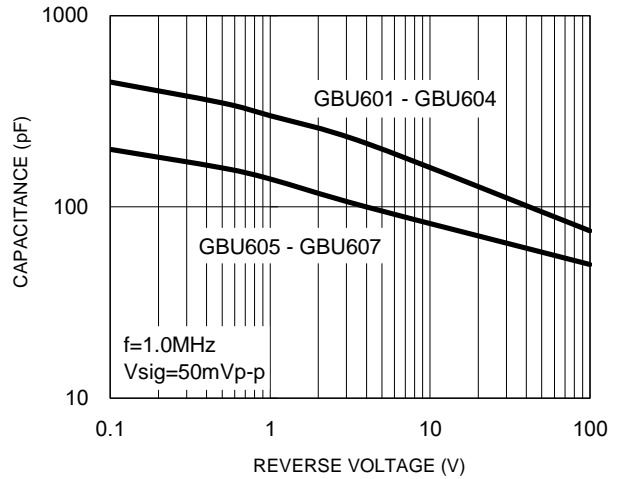
**CHARACTERISTICS CURVES**

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

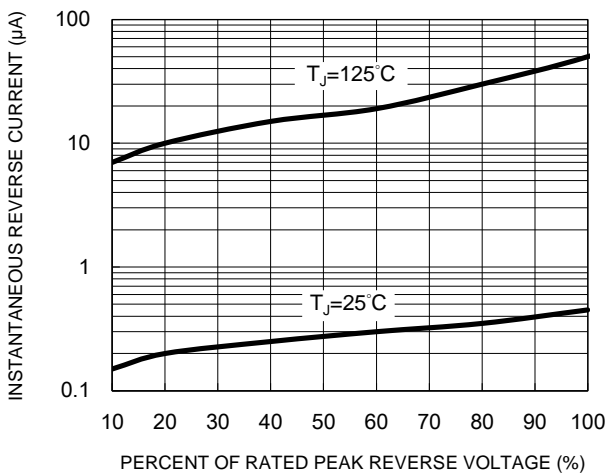
**Fig.1 Forward Current Derating Curve**



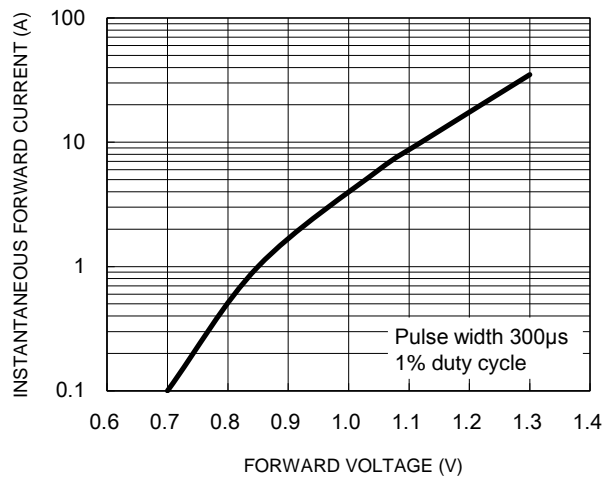
**Fig.2 Typical Junction Capacitance**



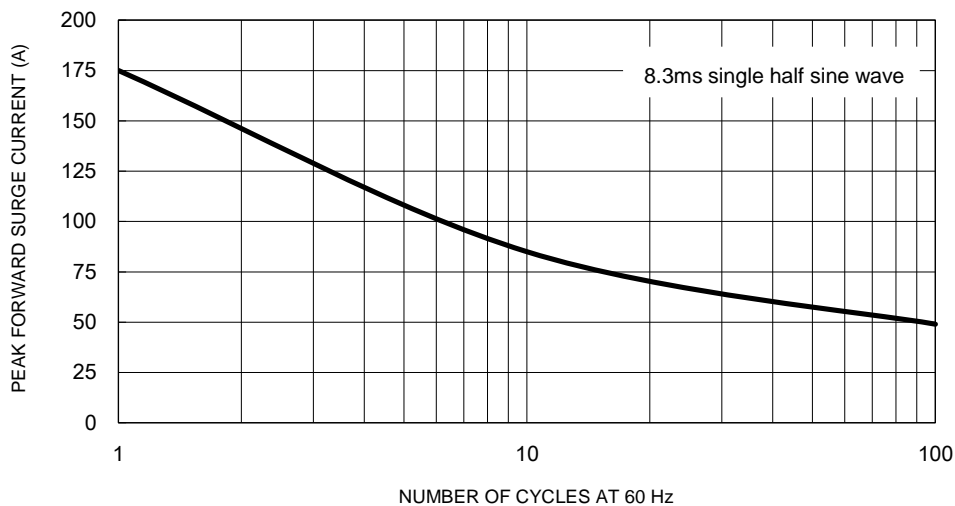
**Fig.3 Typical Reverse Characteristics**



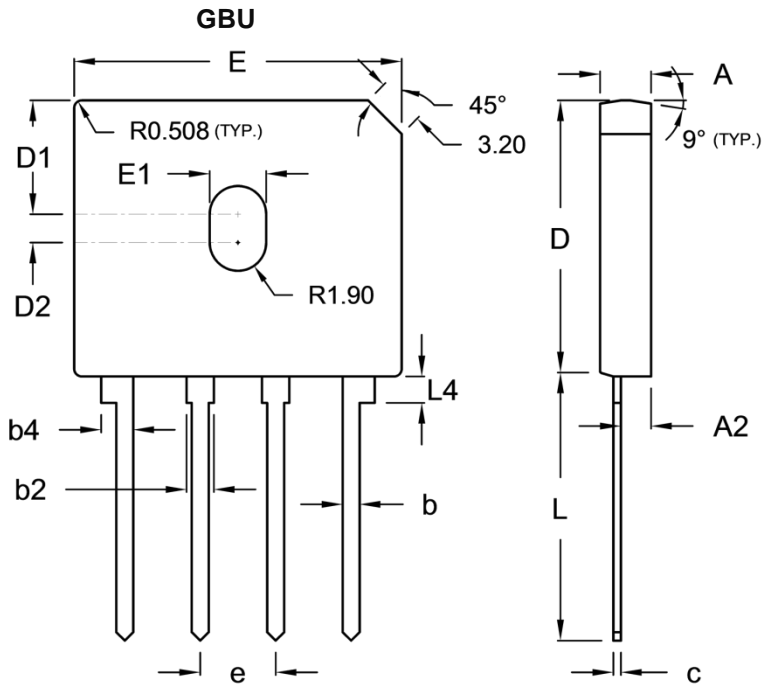
**Fig.4 Typical Forward Characteristics**



**Fig.5 Maximum Non-Repetitive Forward Surge Current**



**PACKAGE OUTLINE DIMENSIONS**



DIM.	Unit (mm)		Unit (inch)	
	Min.	Max.	Min.	Max.
A	3.30	3.56	0.130	0.140
A2	1.90	2.16	0.075	0.085
b	1.02	1.27	0.040	0.050
b2	1.65	2.03	0.065	0.080
b4	2.16	2.54	0.085	0.100
c	0.46	0.56	0.018	0.022
D	18.30	18.80	0.720	0.740
D1	7.40	7.90	0.291	0.311
D2	1.65	2.16	0.065	0.085
E	21.80	22.30	0.858	0.878
E1	3.50	4.10	0.138	0.161
e	4.83	5.33	0.190	0.210
L	17.50	18.00	0.689	0.709
L4	1.52	2.03	0.060	0.080

**MARKING DIAGRAM**



- P/N = Marking Code
- G = Green Compound
- YWW = Date Code
- F = Factory Code